

INNOSCIENCE (ZHUHAI) TECHNOLOGY COMPANY, LTD., AND INNOSCIENCE AMERICA, INC., Petitioner,

v.

EFFICIENT POWER CONVERSION CORPORATION, Patent Owner

Case No. IPR2023-01384 U.S. Patent 10,312,335

PETITIONER'S UPDATED EXHIBIT LIST

Further to 37 C.F.R. § 42.63(e), Petitioner hereby submits a current listing of its exhibits to counsel for Patent Owner. Exhibit 1032 was filed on P-TACTS and served via email to counsel of record for the Patent Owner.

| Exhibits | Description |
|----------|---|
| Ex. 1001 | U.S. Patent No. 10,312,335 B2 to Cao et al. ("the '335 patent") |
| Ex. 1002 | Prosecution History of the '335 patent |
| Ex. 1003 | Declaration of Dr. James Richard Shealy ("Shealy") |
| Ex. 1004 | Curriculum Vitae of Dr. James Richard Shealy |
| Ex. 1005 | Japanese Patent Publication No. JP H11-261053 to Yoshida |
| Ex. 1006 | Certified Translation of Japanese Patent Publication No. JP H11- |
| E 1007 | 261053 to Yoshida ("Yoshida") |
| Ex. 1007 | U.S. Patent Application Publication No. US 2006/0108606 A1 to |
| Ev. 1009 | Saxler et al. ("Saxler") |
| Ex. 1008 | U.S. Patent Application Publication No. US 2007/0007547 A1 to Beach ("Beach") |
| Ex. 1009 | R.V. Shenoy and M. Datta, Effect of Mask Wall Angle on Shape |
| | Evolution during Through-Mask Electrochemical Micromachining, |
| | 143 J. Electrochemical Soc'y, pp. 544-549 (1996) ("Shenoy") |
| Ex. 1010 | U.S. Patent No. 5,905,274 to Ahn et al. ("Ahn") |
| Ex. 1011 | U.S. Patent Application Publication No. US 2010/0258843 A1 to |
| | Lidow et al. ("Lidow") |
| Ex. 1012 | U.S. Patent No. 9,748,347 to Cao et al. ("the '347 patent") |
| Ex. 1013 | Prosecution History of the '347 patent |
| Ex. 1014 | Chua Xu et al., The Leakage Current of the Schottky Contact on the |
| | Mesa Edge of AlGaN/GaN Heterostructure, 28 IEEE Electron |
| | Device Letters, pp. 942-944 (2007) ("Xu") |
| Ex. 1015 | U.S. Patent Application Publication No. US 2002/0066908 A1 to Smith ("Smith") |
| Ex. 1016 | U.S. Patent Application Publication No. US 2006/0273347 A1 to |
| LX. 1010 | Hikita et al. ("Hikita") |
| Ex. 1017 | U.S. Patent Application Publication No. US 2009/0072272 A1 to |
| | Suh et al. ("Suh") |
| Ex. 1018 | X. Hu et al., Enhancement mode AlGaN/GaN HFET with selectively |
| | grown pn junction gate, 36 Electronics Letters, pp. 753-754 (2000) ("Hu") |

| Ex. 1019 | U.S. Patent Application Publication No. US 2005/0087763 A1 to |
|----------|--|
| | Kanda et al. ("Kanda") |
| Ex. 1020 | Yasushiro Uemoto et al., A Normally-off AlGaN/GaN Transistor |
| | with $R_{on}A=2.6\Omega cm^2$ and $BV_{ds}=640V$ Using Conductivity |
| | Modulation, 2006 International Electron Devices Meeting, IEEE |
| | (2006) ("Uemoto") |
| Ex. 1021 | U.S. Patent Application Publication No. US 2006/0019435 A1 to |
| | Sheppard et al. ("Sheppard") |
| Ex. 1022 | Order Granting Defendants' Unopposed Motion for Stay Pending |
| | ITC Proceeding, Case No. 2:23-cv-04026-AB-AS, Central District |
| | of California (July 27, 2023) |
| Ex. 1023 | Dietrich W. Widmann, Metallization for Integrated Circuits Using a |
| | Lift-Off Technique, 11 IEEE Journal of Solid-State Circuits, pp. 466- |
| | 471 (1976) ("Widmann") |
| Ex. 1024 | Reserved |
| Ex. 1025 | Declaration of Kelley Hayes Greenhill |
| Ex. 1026 | Declaration of Shauna Wiest |
| Ex. 1027 | International Publication No. WO 2005/057624 to Beach, published |
| | June 23, 2005 ("Beach-II") |
| Ex. 1028 | Petitioner and Complainant's Proposed Claim Construction, ITC |
| | 337-TA-1366 |
| Ex. 1029 | C. S. Suh et al., "p-GaN/AlGaN/GaN Enhancement-Mode HEMTs, |
| | 2006 64th Device Research Conference, June 2006, pp. 163-164 |
| | ("Suh 2006") |
| Ex. 1030 | Excerpt of the Declaration of Dr. Eric Fred Schubert in Support of |
| | Complainant's Opening Claim Construction Brief, In the Matter of |
| | Certain Semiconductor Devices, and Methods of Manufacturing |
| | Same and Products Containing the Same, ITC Investigation No. |
| | 337-TA-1366 |
| Ex. 1031 | Excerpt of Complainant's Supplemental Responses to Respondents' |
| | Supplemental Invalidity Contentions, <i>In the Matter of Certain</i> |
| | Semiconductor Devices, and Methods of Manufacturing Same and |
| | Products Containing the Same, ITC Investigation No. 337-TA-1366 |
| Ex. 1032 | Hand drawing from Deposition of Dr. James R. Shealy, May 16, |
| | 2024 |
| | I and the second |

Dated: September 10, 2024

By: /Kara A. Specht/
Kara A. Specht, Back-up Counsel
Reg. No. 69,560

CERTIFICATE OF SERVICE

The undersigned hereby certifies that the foregoing **Petitioner's Updated Exhibit List and Exhibit 1032** were served on September 10, 2024, via email directed to counsel of record for the Patent Owner at the following:

Walter D. Davis, Jr. walter.davis@blankrome.com

Dipu Doshi dipu.doshi@blankrome.com

Mark F. Mashack mark.mashack@blankrome.com

Stephen Soffen stephen.soffen@blankrome.com

Cory R. Edwards cory.edwards@blankrome.com

Ameya V. Paradkar arun.paradkar@blankrome.com

Jonathan England jonathan.england@blankrome.com

EPCC-Inno-IPRS@blankrome.com

Dated: September 10, 2024 By: /Daniel E. Doku/

Daniel E. Doku Litigation Legal Assistant FINNEGAN, HENDERSON, FARABOW, GARRETT & DUNNER, LLP